

L Number	Hits	Search Text	DB	Time stamp
1	175	(438/32).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/28 07:37
2	268	(438/31).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/28 07:44
3	386	(438/47).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/28 08:02
4	24973	(nitride and gallium) or gan	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/28 08:03
5	11466	((nitride and gallium) or gan) and grow\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/28 08:03
6	6576	(((nitride and gallium) or gan) and grow\$) and etch\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/28 08:03
7	6197	(((nitride and gallium) or gan) and grow\$) and etch\$) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/28 08:08
8	391	((((nitride and gallium) or gan) and grow\$) and etch\$) and semiconductor) and (lateral adj1 \$grow\$)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/28 08:09